



Opto Plus LED Corp.
1.2" Case Mold Type LED Display
OPD-S12012YG-BW
OPD-S12013YG-BW

● **FEATURES**

- 1.2 inch (30.6 mm) Digit Height.
- Low current operation.
- Case mold type.
- Black face, White segment.
- RoHS compliant, Pb Free.

● **DESCRIPTION**

The OPD-S12012YG-BW & OPD-S12013YG-BW is a 1.2 inch (30.6 mm) height single 7-segment display.

This device utilizes Super Bright Yellow Green LED chip which are made from AlGaInP on a transparent GaAs substrate. The display has Black face, White segment.

● **DEVICE**

PART NO	DESCRIPTION
Super Bright Yellow Green	
OPD-S12012YG-BW	Common Anode
OPD-S12013YG-BW	Common Cathode

RoHS Compliance



Pb free.





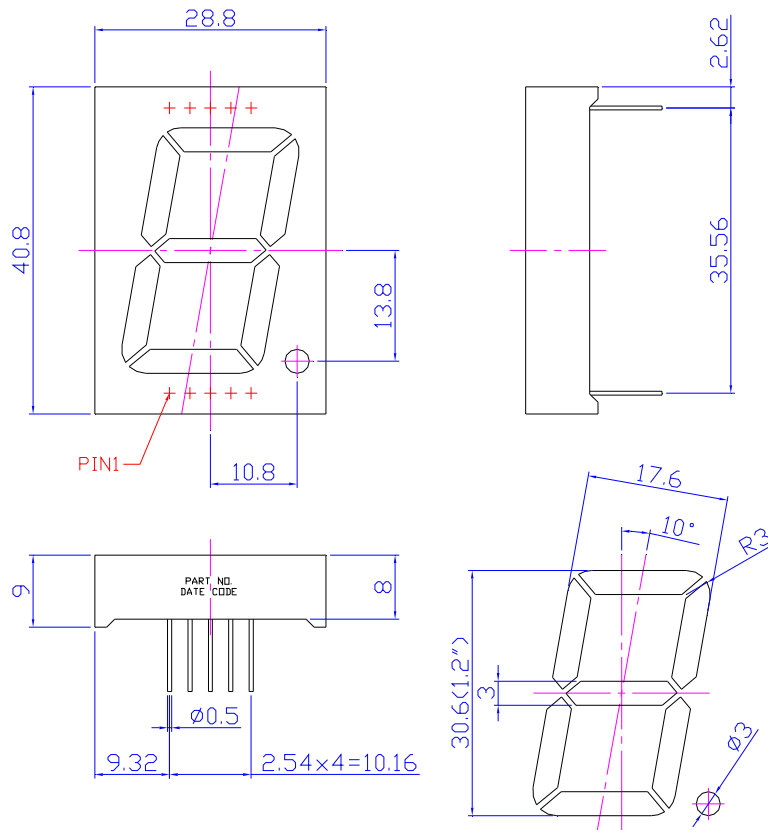
Opto Plus LED Corp.

1.2" Case Mold Type LED Display

OPD-S12012YG-BW

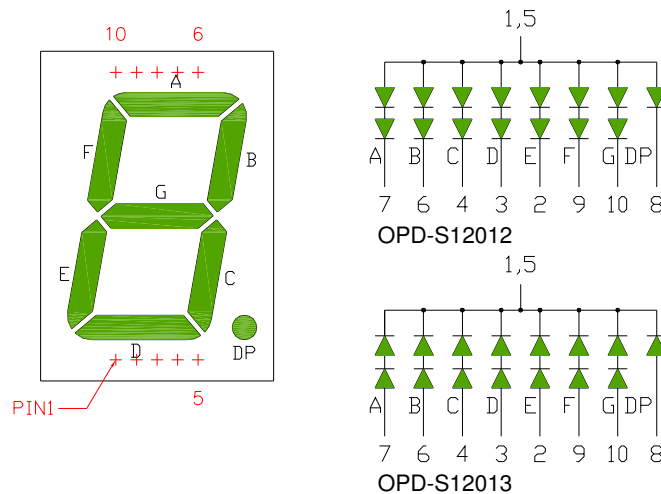
OPD-S12013YG-BW

MECHANICAL DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

TYPICAL INTERNAL EQUIVALENT CIRCUIT





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● **YG: SUPER BRIGHT YELLOW GREEN (AlGaInP/GaAs)**

ABSOLUTE MAXIMUM RATING AT Ta=25°C

Parameter	Symbol	Super Bright Yellow Green	Unit
Power dissipation per dice	P _{AD}	85	mW
Derating liner from 25 °C per dice	-	0.42	mA / °C
Continuous forward current per dice	I _{AF}	30	mA
Peak current per dice (duty cycle 1/10, 1kHz)	I _{PF}	120	mA
Reverse voltage per dice	V _R	5	V
Operating temperature	T _{OPR}	-25 to +85	°C
Storage temperature	T _{STG}	-25 to +85	°C

ELECTRICAL - OPTICAL CHARACTERISTICS AT Ta=25°C

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward voltage per Segment (DP)	V _F	I _F =20mA	-	4.2 (2.1)	5.2 (2.6)	V
Reverse current per Segment (DP)	I _R	V _R =10V (V _R =5V)	-	-	10	μA
Peak wavelength	λ _P	I _F =20mA	-	573	-	nm
Dominant wavelength	λ _D	I _F =20mA	-	571	-	nm
Luminous intensity	I _V	I _F =20mA	-	35	-	mcd
Spectral radiation bandwidth	Δλ	I _F =20mA	-	20	-	nm



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● YG: SUPER BRIGHT YELLOW GREEN (AlGaInP/GaAs) CURVE

Typical Electro-optical Characteristic Curves
(25 °C Free Air Temperature Unless Otherwise Specified)

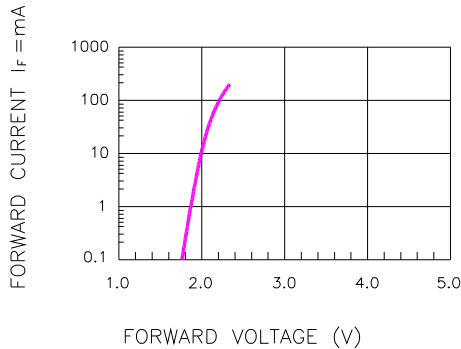


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE



Fig.2 RELATIVE INTENSITY VS. FORWARD CURRENT



Fig.3 FORWARD VOLTAGE VS. TEMPERATURE

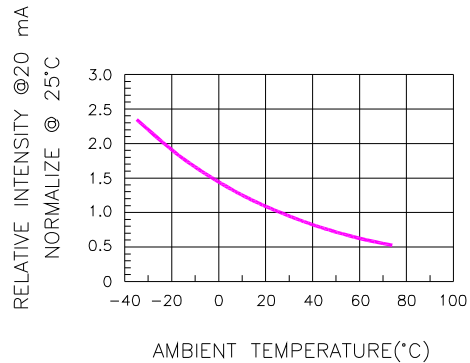


Fig.4 RELATIVE INTENSITY VS. TEMPERATURE



Fig.5 RELATIVE INTENSITY VS. WAVELENGTH

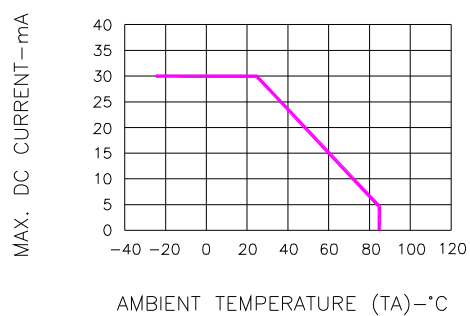


Fig.6 MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE



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● **RECOMMEND SOLDERING PROFILE**



● **SOLDERING IRON**

Basic spec is ≤ 4 sec when 260°C. If temperature is higher, time should be shorter (+10°C→1 sec). Power dissipation of Iron should be smaller than 15W, and temperature should be controllable. Surface temperature of the device should be under 230°C.

● **REWORK**

Customer must finish rework within ≤ 4 sec under 245°C.